

# DL-3147-041

# Index Guided AlGaInP Laser Diode

### Overview

DL-3147-041 is index guided 645 nm (Typ.) AlGaInP laser diode with low threshold current and high operating temperature. The low threshold current and high operating temperature are achieved by a strained multiple quantum well active layer. DL-3147-041 is suitable for applications such as bar-code reader, optical disc systems and other optical information systems.

#### **Features**

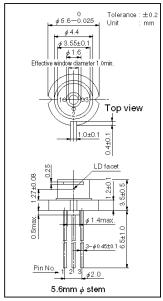
• Short wavelength : 645 nm (Typ.)• Low threshold current : Ith = 45 mA (Typ.)• High operating temperature :  $60 ^{\circ}\text{C}$  at 5 mW

· TE mode

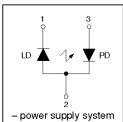
### **Absolute Maximum Ratings at Tc=25℃**

Parameter		Symbol	Ratings	Unit	
Light Output		Po	5	mW	
Reverse Voltage	Laser	Vr	2	V	
lieverse verage	PIN	, 11	30	·	
Operating Temperature		Topr	-10 to +60	${\mathbb C}$	
Storage Temperature		Tstg	-40 to +85	$^{\circ}$	

# Package Dimensions



## **Electrical Connection**

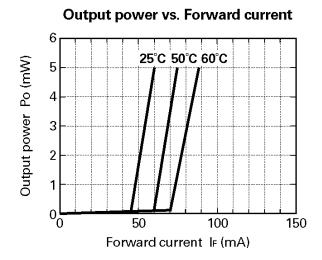


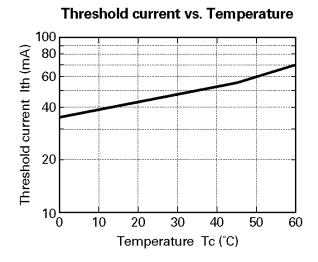
## Electrical and Optical Characteristics at Tc=25 $^{\circ}$ C

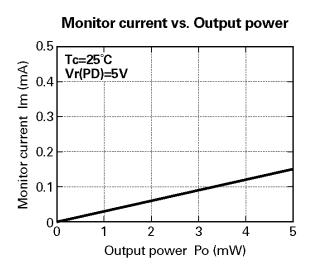
Parai	meter	Symbol	Condition	Min.	Тур.	Max.	Unit
Threshol	d Current	Ith	CW	25	45	60	mA
Operating	g Current	Iop	Po=5mW	40	60	80	mA
Operating	g Voltage	Vop	Po=5mW	2.0	2.2	2.5	V
Lasing W	avelength	λp	Po=5mW	635	645	655	nm
Beam 💥 )	Perpendicular	$\theta \perp$	Po=5mW	25	30	40	deg.
Divergence	Parallel	θ//	Po=5mW	7.0	7.5	10	deg.
Off Axis	Perpendicular	$\Delta \theta \perp$	-	-	-	±3	deg.
Angle	Parallel	$\Delta  heta$ //	-	_	=	±2	deg.
Differential	l Efficiency	dPo/dIop	-	0.15	0.35	0.8	mW/mA
Monitoring O	utput Current	Im	Po=5mW	0.05	0.15	0.5	mA
Astign	natism	As	Po=5mW	_	8	_	μm

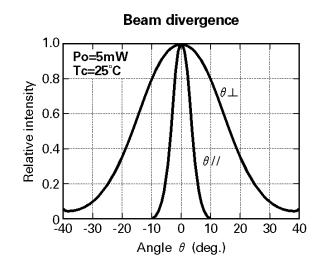
<sup>※)</sup> Full angle at half maximum note: The above product specifications are subject to change without notice.

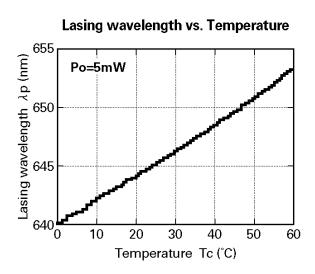
### Characteristics

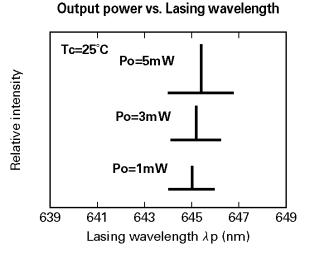














- 1. No products described or contained herein are intended for use in surgical implants, life-support systems, aerospace equipment, nuclear power control systems, vehicles, disaster / crime-prevention equipment or the like, and the failure of which may directly or indirectly cause injury, death or property loss.
- 2. Anyone purchasing any products described or contained herein for an above-mentioned use shall:
  - 1) Accept full responsibility and indemnify and defend SANYO ELECTRIC CO.,LTD., it's affiliates, subsidiaries and distributors or any of their officers and employees, jointly and severally, against any and all claims and litigation and all damages, costs and expenses associated with such use.
  - 2) Not impose any responsibility for any fault or negligence which may be cited in any such claim or litigation on SANYO ELECTRIC CO., LTD., it's affiliates, subsidiaries and distributors or any of their officers and employees jointly or severally.
- 3. Information (including circuit diagrams and circuit parameters) disclosed herein is for example only; it is not guaranteed for mass production, SANYO believes the information disclosed herein is accurate and reliable, but no guarantees are made or implied regarding it's use or any infringements of intellectual property rights or other rights of third parties.

# Precautionary instructions in handling gallium arsenic products

Special precautions must be taken in handling this product because it contains, gallium arsenic, which is designated as a toxic substance by law. Be sure to adhere strictly to all applicable laws and regulations enacted for this substance, particularly when it comes to disposal.

Manufactured by; Tottori SANYO Electric Co., Ltd.

Electronics Device Bussiness Headquaters LED Division 5-318, Tachikawa-cho, Tottori City, 680 Japan TEL: +81-857-21-2137 FAX: +81-857-21-2161